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# 100 mA, 5.0 V Voltage Regulator and Supervisory Circuit for Microprocessors

The MC34160 Series is a voltage regulator and supervisory circuit containing many of the necessary monitoring functions required in microprocessor based systems. It is specifically designed for appliance and industrial applications, offering the designer a cost effective solution with minimal external components. These integrated circuits feature a 5.0 V/100 mA regulator with short circuit current limiting, pinned out 2.6 V bandgap reference, low voltage reset comparator, power warning comparator with programmable hysteresis, and an uncommitted comparator ideally suited for microprocessor line synchronization.

Additional features include a chip disable input for low standby current, and internal thermal shutdown for over temperature protection.

These devices are contained in a 16 pin dual-in-line heat tab plastic package for improved thermal conduction.

#### **Features**

- 5.0 V Regulator Output Current in Excess of 100 mA
- Internal Short Circuit Current Limiting
- Pinned Out 2.6 V Reference
- Low Voltage Reset Comparator
- Power Warning Comparator with Programmable Hysteresis
- Uncommitted Comparator
- Low Standby Current
- Internal Thermal Shutdown Protection
- Heat Tab Power Package
- Pb-Free Packages are Available\*

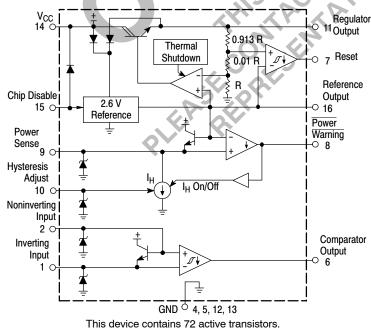


Figure 4 Depresentative Block Discret

Figure 1. Representative Block Diagram

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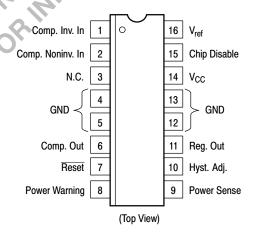


SOIC-16WB DW SUFFIX CASE 751G



PDIP-16 P SUFFIX CASE 648C

#### **PIN CONNECTIONS**



#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 9 of this data sheet.

## **DEVICE MARKING INFORMATION**

See general marking information in the device marking section on page 9 of this data sheet.

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### **MAXIMUM RATINGS**

| Rating  | Symb                    | ol Value                | Unit |
|---|-------------------------|-------------------------|------|
| Power Supply Voltage  | V <sub>CC</sub>         | 40                      | V    |
| Chip Disable Input Voltage (Pin 15, Note 1)   | V <sub>CD</sub>         | −0.3 to V <sub>CC</sub> | ; V  |
| Comparator Input Current (Pins 1, 2, 9)   | I <sub>in</sub>         | -2.0 to +2.0            | ) mA |
| Comparator Output Voltage (Pins 6, 7, 8)  | V <sub>O</sub>          | 40                      | V    |
| Comparator Output Sink Current (Pins 6, 7, 8)   | I <sub>Sink</sub>       | 10                      | mA   |
| Power Dissipation and Thermal Characteristics P Suffix, Dual-In-Line Case 648C Thermal Resistance, Junction-to-Air Thermal Resistance, Junction-to-Case (Pins 4, 5, 12, 13) DW Suffix, Surface Mount Case 751G Thermal Resistance, Junction-to-Air Thermal Resistance, Junction-to-Case (Pins 4, 5, 12, 13) | Reuze<br>Reuze<br>Reuze | 15                      | °C/W |
| Operating Junction Temperature  | TJ                      | +150                    | °C   |
| Operating Ambient Temperature   | MC34160<br>MC33160      | 0 to +70<br>-40 to +85  | °C   |
| Storage Temperature Range   | T <sub>stg</sub>        | -65 to +150             | ) °C |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

**ELECTRICAL CHARACTERISTICS** ( $V_{CC}$  = 30 V,  $I_{O}$  = 10 mA,  $I_{ref}$  = 100  $\mu$ A) For typical values  $T_{A}$  = 25°C, for min/max values  $T_{A}$  is the operating ambient temperature range that applies [Notes 2 and 3], unless otherwise noted.)

| Characteristics   | Symbol   | Min               | Тур  | Max                              | Unit |
|---|--|-------------------|--|----------------------------------|------|
| REGULATOR SECTION   | 14. 1  |                   |  |                                  |      |
| Total Output Variation (V <sub>CC</sub> = 7.0 V to 40 V, $I_O$ = 1.0 mA to 100 mA, $T_A$ = $T_{low}$ to $T_{high}$ )        | $V_{O}$  | 4.75              | 5.0  | 5.25                             | V    |
| Line Regulation (V <sub>CC</sub> = 7.0 V to 40 V, T <sub>A</sub> = 25°C)  | Reg <sub>line</sub>                                  | -                 | 5.0  | 40                               | mV   |
| Load Regulation (I <sub>O</sub> = 1.0 V to 100 mA, T <sub>A</sub> = 25°C)   | Reg <sub>load</sub>                                  | -                 | 20   | 50                               | mV   |
| Ripple Rejection ( $V_{CC}$ = 25 V to 35 V, $I_{O}$ = 40 mA, f = 120 Hz, $T_{A}$ = 25°C)                                    | RR   | 50                | 65   | -                                | dB   |
| REFERENCE SECTION   |  |                   |  |                                  |      |
| Total Output Variation ( $V_{CC}$ = 7.0 to 40 V, $I_{O}$ = 0.1 mA to 2.0 mA, $T_{A}$ = $T_{low}$ to $T_{high}$ )            | $V_{ref}$  | 2.47              | 2.6  | 2.73                             | V    |
| Line Regulation (V <sub>CC</sub> = 5.0 V to 40 V, T <sub>A</sub> = 25°C)  | Reg <sub>line</sub>                                  | -                 | 2.0  | 20                               | mV   |
| Load Regulation (I <sub>O</sub> = 0.1 mA to 2.0 mA, T <sub>A</sub> = 25°C)  | Reg <sub>load</sub>                                  | -                 | 4.0  | 30                               | mV   |
| RESET COMPARATOR  |  |                   |  |                                  |      |
| Threshold Voltage  High State Output (Pin 11 Increasing)  Low State Output (Pin 11 Decreasing)  Hysteresis                  | V <sub>IH</sub><br>V <sub>IL</sub><br>V <sub>H</sub> | -<br>4.55<br>0.02 | (V <sub>O</sub> -0.11)<br>(V <sub>O</sub> -0.18)<br>0.07 | (V <sub>O</sub> -0.05)<br>-<br>- | ٧    |
| Output Sink Saturation (V <sub>CC</sub> = 4.5 V, I <sub>Sink</sub> = 2.0 mA)  | V <sub>OL</sub>                                      | -                 | -  | 0.4                              | V    |
| Output Off-State Leakage (V <sub>OH</sub> = 40 V)   | I <sub>OH</sub>                                      | -                 | _  | 4.0                              | μΑ   |
| POWER WARNING COMPARATOR  |  |                   |  |                                  |      |
| Input Offset Voltage  | V <sub>IO</sub>                                      | -                 | 1.2  | 10                               | mV   |
| Input Bias Current (V <sub>Pin 9</sub> = 3.0 V)   | I <sub>IB</sub>                                      | -                 | -  | 0.5                              | μА   |
| Input Hysteresis Current ( $V_{Pin \ 9} = V_{ref} - 100 \text{ mV}$ ) $R_{Pin \ 10} = 24 \text{ k}$ $R_{Pin \ 10} = \infty$ | I <sub>H</sub>                                       | 40<br>4.5         | 50<br>7.5  | 60<br>11                         | μΑ   |
| Output Sink Saturation (I <sub>Sink</sub> = 2.0 mA)   |  | -                 | 0.13   | 0.4                              | V    |
| Output Off-State Leakage (V <sub>OH</sub> = 40 V)   |  | -                 | -  | 4.0                              | μΑ   |

<sup>2.</sup>  $T_{lo} = {0 \circ C \text{ for MC34160} \atop -40 \circ C \text{ for MC33160}}$   $T_{high} = {70 \circ C \text{ for MC34160} \atop 85 \circ C \text{ for MC33160}}$ 

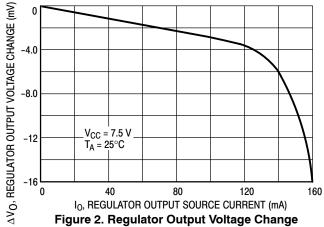
<sup>1.</sup> The maximum voltage range is -0.3 V to  $V_{CC}$  or +35 V, whichever is less.

<sup>3.</sup> Low duty cycle pulse testing techniques are used during test to maintain junction temperature as close to ambient as possible.

**ELECTRICAL CHARACTERISTICS** (continued) ( $V_{CC} = 30 \text{ V}$ ,  $I_{O} = 10 \text{ mA}$ ,  $I_{ref} = 100 \text{ }\mu\text{A}$ ) For typical values  $T_{A} = 25^{\circ}\text{C}$ , for min/max values T<sub>A</sub> is the operating ambient temperature range that applies [Notes 4 and 5], unless otherwise noted.)

| Characteristics                                     |   | Symbol                             | Min                    | Тур         | Max         | Unit |
|---|---|------------------------------------|------------------------|-------------|-------------|------|
| UNCOMMITTED COMPARATOR                              |   |                                    |                        |             |             |      |
| Input Offset Voltage (Output Transition Lov         | v to High)  | V <sub>IO</sub>                    | -                      | -           | 20          | mV   |
| Input Hysteresis Voltage (Output Transition         | n High to Low)  | I <sub>H</sub>                     | 140                    | 200         | 260         | mV   |
| Input Bias Current (V <sub>Pin 1, 2</sub> = 2.6 V)  |   | I <sub>IB</sub>                    | -                      | -           | -1.0        | μΑ   |
| Input Common Mode Voltage Range                     |   | V <sub>ICR</sub>                   | 0.6 to 5.0             | -           | -           | V    |
| Output Sink Saturation (I <sub>Sink</sub> = 2.0 mA) |   | V <sub>OL</sub>                    | -                      | 0.13        | 0.4         | V    |
| Output Off-State Leakage (V <sub>OH</sub> = 40 V)   |   | loh                                | -                      | -           | 4.0         | μΑ   |
| TOTAL DEVICE  |   |                                    |                        |             |             |      |
| Chip Disable Threshold Voltage (Pin 15)             | High State (Chip Disabled)<br>Low State (Chip Enabled)                      | V <sub>IH</sub><br>V <sub>IL</sub> | 2.5                    | -           | 0.8         | V    |
| Chip Disable Input Current (Pin 15)                 | High State (V <sub>in</sub> = 2.5 V)<br>Low State (V <sub>in</sub> = 0.8 V) | I <sub>IH</sub><br>I <sub>IL</sub> | -<br>-                 | -           | 100<br>30   | μΑ   |
| Chip Disable Input Resistance (Pin 15)              |   | R <sub>in</sub>                    | 50                     | 100         | _           | kΩ   |
| Operating Voltage Range                             | V <sub>O</sub> (Pin 11) Regulated<br>V <sub>ref</sub> (Pin 16) Regulated    | V <sub>CC</sub>                    | 7.0 to 40<br>5.0 to 40 | E           | -<br>-      | V    |
| Power Supply Current                                | Standby (Chip Disable High State)<br>Operating (Chip Disable Low State)     | Icc                                | V13                    | 0.18<br>1.5 | 0.35<br>3.0 | mA   |

<sup>4.</sup> T<sub>lo</sub> = 0°C for MC34160 T<sub>high</sub> = 70°C for MC34160 85°C for MC33160
5. Low duty cycle pulse testing techniques are used during test to maintain junction temperature as close to ambient as possible. 0°C for MC34160 70°C for MC34160  $T_{high} =$ -40°C for MC33160 85°C for MC33160



versus Source Current

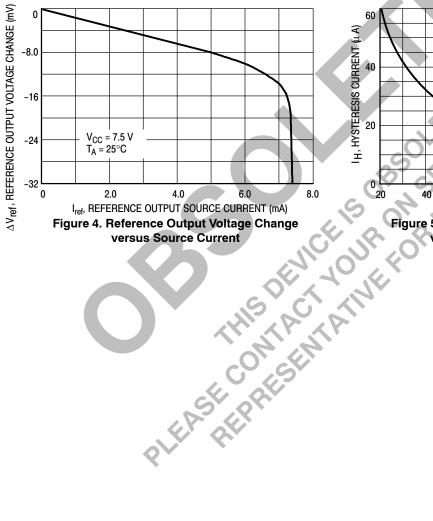


Figure 4. Reference Output Voltage Change

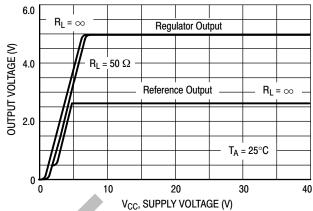


Figure 3. Reference and Regulator Output versus Supply Voltage

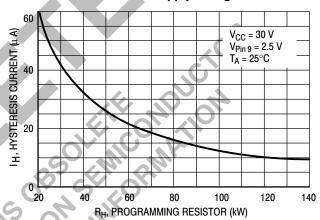


Figure 5. Power Warning Hysteresis Current versus Programming Resistor

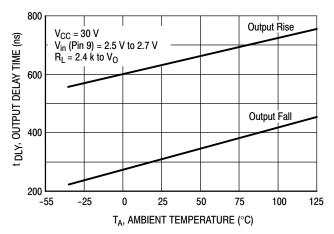


Figure 6. Power Warning Comparator Delay versus Temperature

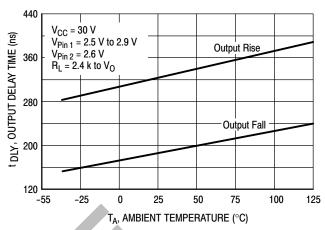


Figure 7. Uncommitted Comparator Delay versus Temperature

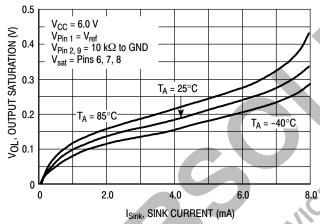


Figure 8. Comparator Output Saturation versus Sink Current

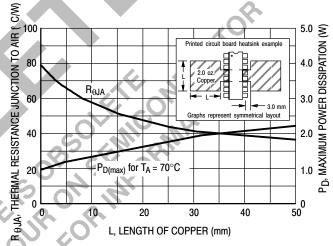


Figure 9. P Suffix (DIP-16) Thermal Resistance and Maximum Power Dissipation versus P.C.B. Copper Length

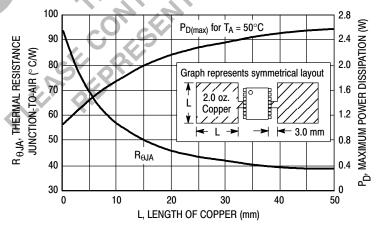


Figure 10. DW Suffix (SOP-16L) Thermal Resistance and Maximum Power Dissipation versus P.C.B. Copper Length

#### PIN FUNCTION DESCRIPTION

| Pin          | Function                      | Description   |  |
|--------------|-------------------------------|---|--|
| 1            | Comparator Inverting Input    | This is the Uncommitted Comparator Inverting input. It is typically connected to a resistor divider to monitor a voltage.   |  |
| 2            | Comparator Noninverting Input | This is the Uncommitted Comparator Noninverting input. It is typically connected to a reference voltage.  |  |
| 3            | N.C.                          | No connection. This pin is not internally connected.  |  |
| 4, 5, 12, 13 | GND                           | These pins are the control circuit grounds and are connected to the source and load ground returns. They are part of the IC lead frame and can be used for heatsinking. |  |
| 6            | Comparator Output             | This is the Uncommitted Comparator output. It is an open collector sink-only output requiring a pullup resistor.  |  |
| 7            | Reset                         | This is the Reset Comparator output. It is an open collector sink-only output requiring a pullup resistor.  |  |
| 8            | Power Warning                 | This is the Power Warning Comparator output. It is an open collector sink-only output requiring a pullup resistor.  |  |
| 9            | Power Sense                   | This is the Power Warning Comparator noninverting input. It is typically connected to a resistor divider to monitor the input power source voltage.                     |  |
| 10           | Hysteresis Adjust             | The Power Warning Comparator hysteresis is programmed by a resistor connected from this pin to ground.  |  |
| 11           | Regulator Output              | This is the 5.0 V Regulator output.   |  |
| 14           | V <sub>CC</sub>               | This pin is the positive supply input of the control IC.  |  |
| 15           | Chip Disable                  | This input is used to switch the IC into a standby mode turning off all outputs.  |  |
| 16           | V <sub>ref</sub>              | This is the 2.6 V Reference output. It is intended to be used in conjunction with the Power Warning and Uncommitted comparators.  |  |

# OPERATING DESCRIPTION

The MC34160 series is a monolithic voltage regulator and supervisory circuit containing many of the necessary monitoring functions required in microprocessor based systems. It is specifically designed for appliance and industrial applications, offering the designer a cost effective solution with minimal external components. These devices are specified for operation over an input voltage of 7.0 V to 40 V, and with a junction temperature of  $-40^{\circ}$  to  $+150^{\circ}$ C. A typical microprocessor application is shown in Figure 11.

## Regulator

The 5.0 V regulator is designed to source in excess of 100 mA output current and is short circuit protected. The output has a guaranteed tolerance of  $\pm 5.0\%$  over line, load, and temperature. Internal thermal shutdown circuitry is included to limit the maximum junction temperature to a safe level. When activated, typically at  $170^{\circ}$ C, the regulator output turns off.

In specific situations a combination of input and output bypass capacitors may be required for regulator stability. If the regulator is located an appreciable distance ( $\geq 4''$ ) from the supply filter, an input bypass capacitor ( $C_{in}$ ) of 0.33  $\mu F$  or greater is suggested. Output capacitance values of less than 5.0 nF may cause regulator instability at light load ( $\leq 1.0$  mA) and cold temperature. An output bypass

capacitor of  $0.1~\mu F$  or greater is recommended to ensure stability under all load conditions. The capacitors selected must provide good high frequency characteristics.

Good construction techniques should be used to minimize ground loops and lead resistance drops since the regulator does not have external sense inputs.

#### Reference

The 2.6 V bandgap reference is short circuit protected and has a guaranteed output tolerance of  $\pm 5.0\%$  over line, load, and temperature. It is intended to be used in conjunction with the Power Warning and Uncommitted comparator. The reference can source in excess of 2.0 mA and sink a maximum of 10  $\mu A.$  For additional current sinking capability, an external load resistor to ground must be used

Reference biasing is internally derived from either  $V_{\rm CC}$  or  $V_{\rm O}$ , allowing proper operation if either drops below nominal.

#### **Chip Disable**

This input is used to switch the IC into a standby mode. When activated, internal biasing for the entire die is removed causing all outputs to turn off. This reduces the power supply current ( $I_{CC}$ ) to less than 0.3 mA.

#### Comparators

Three separate comparators are incorporated for voltage monitoring. Their outputs can provide diagnostic information to the microprocessor, preventing system malfunctions.

The Reset Comparator Inverting Input is internally connected to the 2.6 V reference while the Noninverting Input monitors  $V_O$ . The Reset Output is active low when  $V_O$  falls approximately 180 mV below its regulated voltage. To prevent erratic operation when crossing the comparator threshold, 70 mV of hysteresis is provided.

The Power Warning Comparator is typically used to detect an impending loss of system power. The Inverting Input is internally connected to the reference, fixing the threshold at 2.6 V. The input power source  $V_{in}$  is monitored by the Noninverting Input through the  $R_1/R_2$  divider (Figure 11). This input features an adjustable  $10~\mu A$  to  $50~\mu A$  current sink  $I_H$  that is programmed by the value selected for resistor  $R_H$ . A default current of 6.5  $\mu A$  is provided if  $R_H$  is omitted. When the comparator input falls below 2.6 V, the current sink is activated. This produces hysteresis if  $V_{in}$  is monitored through a series resistor  $(R_1)$ . The comparator thresholds are defined as follows:

$$\begin{split} V_{th(lower)} &= V_{ref} & \left(1 \,+\, \frac{R1}{R_2}\right) \,-\, I_{IB}\,R_1 \\ V_{th(upper)} &= V_{ref} & \left(1 \,+\, \frac{R1}{R_2}\right) \,+\, I_{H}\,R_1 \end{split}$$

The nominal hysteresis current  $I_H$  equals 1.2  $V/R_H$  (Figure 5).

The Uncommitted Comparator can be used to synchronize the microprocessor with the ac line signal for timing functions, or for synchronous load switching. It can also be connected as a line loss detector as shown in Figure 12. The comparator contains 200 mV of hysteresis preventing erratic output behavior when crossing the input threshold.

The Power Warning and Uncommitted Comparators each have a transistor base–emitter connected across their inputs. The base input normally connects to a voltage reference while the emitter input connects to the voltage to be monitored. The transistor limits the negative excursion on the emitter input to – 0.7 V below the base input by supply current from  $V_{CC}$ . This clamp current will prevent forward biasing the IC substrate. Zener diodes are connected to the comparator inputs to enhance the ICs electrostatic discharge capability. Resistors  $R_1$  and  $R_{in}$  must limit the input current to a maximum of  $\pm 2.0$  mA.

Each comparator output consists of an open collector NPN transistor capable of sinking 2.0 mA with a saturation voltage less than 0.4 V, and standing off 40 V with minimal leakage. Internal bias for the Reset and Power Warning Comparators is derived from either  $V_{CC}$  or the regulator output to ensure functionality when either is below nominal.

## **Heat Tab Package**

The MC34160 is contained in a 16 lead plastic dual-in-line package in which the die is mounted on a special Heat Tab copper alloy lead frame. This tab consists of the four center ground pins that are specifically designed to improve thermal conduction from the die to the surrounding air. The pictorial in Figure 9 shows a simple but effective method of utilizing the printed circuit board medium as a heat dissipator by soldering these tabs to an adequate area of copper foil. This permits the use of standard board layout and mounting practices while having the ability to more than halve the junction to air thermal resistance. The example and graph are for a symmetrical layout on a single sided board with one ounce per square foot copper.

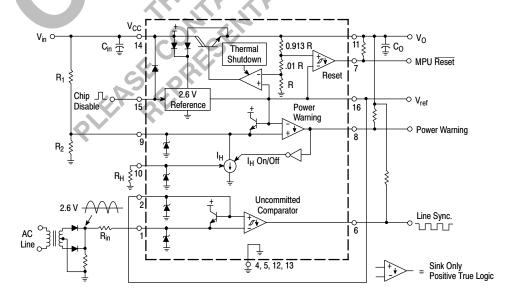


Figure 11. Typical Microprocessor Application

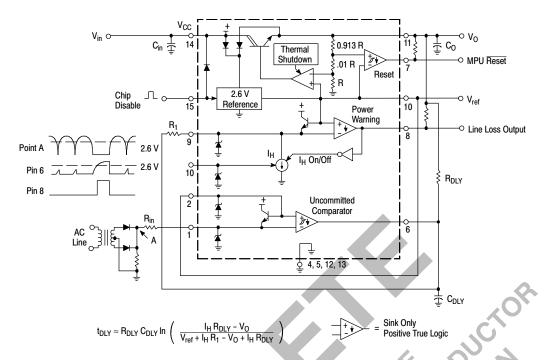


Figure 12. Line Loss Detector Application

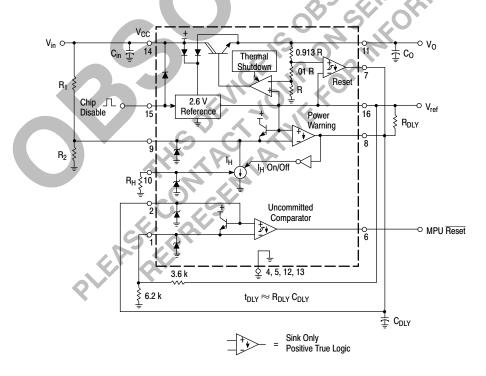


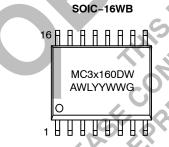
Figure 13. Time Delayed Microprocessor Reset

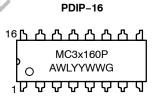
#### **ORDERING INFORMATION**

| Device       | Operating Temperature Range                         | Package                | Shipping <sup>†</sup>    |
|--------------|---|------------------------|--------------------------|
| MC34160DW    |   | SOIC-16WB              | 47 Units / Rail          |
| MC34160DWG   |   | SOIC-16WB<br>(Pb-Free) | 47 Units / Rail          |
| MC34160DWR2  |   | SOIC-16WB              | 1000 Units / Tape & Reel |
| MC34160DWR2G | $T_A = 0^{\circ} \text{ to } +70^{\circ}\text{C}$   | SOIC-16WB<br>(Pb-Free) | 1000 Units / Tape & Reel |
| MC34160P     |   | PDIP-16                | 25 Units / Rail          |
| MC34160PG    |   | PDIP-16<br>(Pb-Free)   | 25 Units / Rail          |
| MC33160DW    |   | SOIC-16WB              | 47 Units / Rail          |
| MC33160DWG   |   | SOIC-16WB<br>(Pb-Free) | 47 Units / Rail          |
| MC33160DWR2  |   | SOIC-16WB              | 1000 Units / Tape & Reel |
| MC33160DWR2G | $T_A = -40^{\circ} \text{ to } +85^{\circ}\text{C}$ | SOIC-16WB<br>(Pb-Free) | 1000 Units / Tape & Reel |
| MC33160P     |   | PDIP-16                | 25 Units / Rail          |
| MC33160PG    |   | PDIP-16<br>(Pb-Free)   | 25 Units / Rail          |

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# MARKING DIAGRAMS





MC3x160 = Device Code

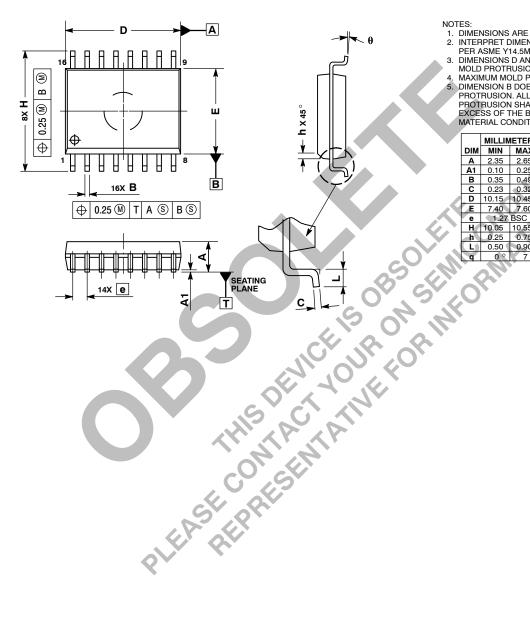
DW = SOIC-16 P = PDIP-16 x = 4 or 3

A = Assembly Location

WL = Wafer Lot
 YY = Year
 WW = Work Week
 G = Pb-Free Package

#### PACKAGE DIMENSIONS

SOIC-16 WB **DW SUFFIX** PLASTIC PACKAGE CASE 751G-03 ISSUE C



#### NOTES:

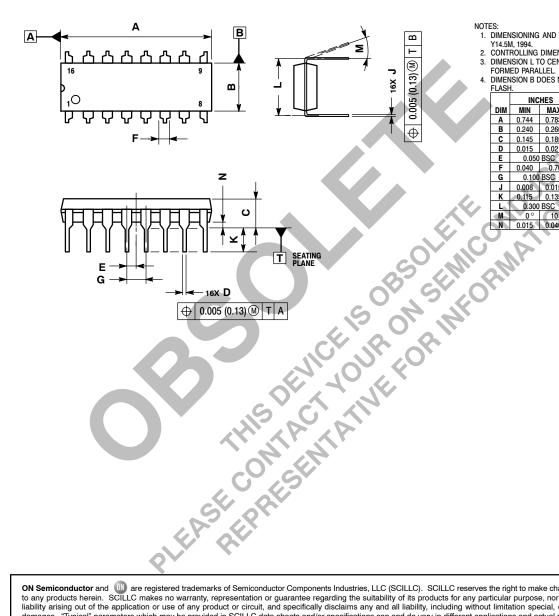
- NOTES:

  1. DIMENSIONS ARE IN MILLIMETERS.
  2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
  3. DIMENSIONS D AND E DO NOT INLCUDE MOLD PROTRUSION.
  4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
  5. DIMENSION B DOES NOT INCLUDE ANMBAR PROTRUSION ALL OWARLE DAMBAR PROTRUSION. PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF THE B DIMENSION AT MAXIMUM MATERIAL CONDITION.

|     | MILLIN | IETERS |
|-----|--------|--------|
| DIM | MIN    | MAX    |
| Α   | 2.35   | 2.65   |
| A1  | 0.10   | 0.25   |
| В   | 0.35   | 0.49   |
| С   | 0.23   | 0.32   |
| D   | 10.15  | 10.45  |
| E   | 7.40   | 7.60   |
| е   | 1.27   | BSC    |
| H   | 10.05  | 10.55  |
| h   | 0.25   | 0.75   |
| L   | 0.50   | 0.90   |
| q   | 0 °    | 7 °    |

#### PACKAGE DIMENSIONS

#### PDIP-16 **P SUFFIX** PLASTIC PACKAGE CASE 648C-04 ISSUE D



#### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- CONTROLLING DIMENSION: INCH.
  DIMENSION L TO CENTER OF LEADS WHEN
- FORMED PARALLEL.
  DIMENSION B DOES NOT INCLUDE MOLD

|     | INCHES            |       | MILLIMETER |       |
|-----|-------------------|-------|------------|-------|
| DIM | MIN               | MAX   | MIN        | MAX   |
| Α   | 0.744             | 0.783 | 18.90      | 19.90 |
| В   | 0.240             | 0.260 | 6.10       | 6.60  |
| С   | 0.145             | 0.185 | 3.69       | 4.69  |
| D   | 0.015             | 0.021 | 0.38       | 0.53  |
| Е   | 0.050 BSC 1.27 BS |       | BSC        |       |
| F   | 0.040             | 0.70  | 1.02       | 1.78  |
| G   | 0.100             | BSC   | 2.54       | BSC   |
| J   | 0.008             | 0.015 | 0.20       | 0.38  |
| K   | 0.115             | 0.135 | 2.92       | 3.43  |
| L   | 0.300 BSC         |       | 7.62       | BSC   |
| M   | 0°                | 10°   | 0°         | 10°   |
| N   | 0.015             | 0.040 | 0.39       | 1.01  |

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